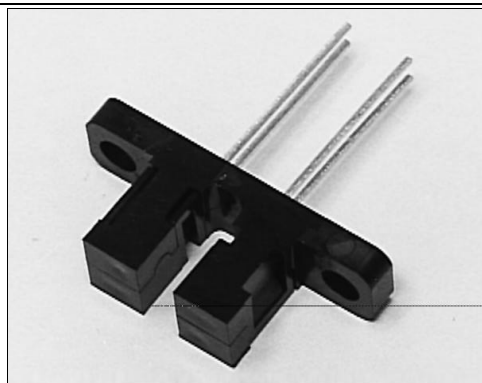


Transmissive Sensor

FEATURES

- Phototransistor output
- Accurate position sensing
- Choice of detector aperture
- 0.125 in.(3.18 mm) slot width
- Dust protective housing



INFRA-40.TIF

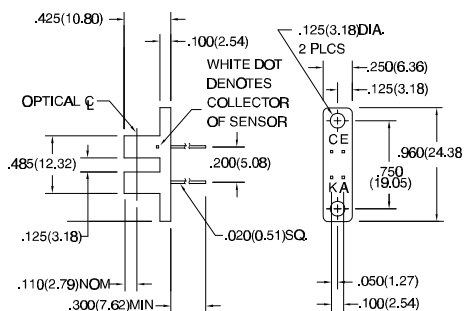
DESCRIPTION

The HOA1879 series consists of an infrared emitting diode facing an NPN silicon phototransistor encased in a black IR transmissive thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. The HOA1879 series employs an IR transmissive housing which features smooth optical faces without external aperture openings; this feature is desirable when aperture blockage from airborne contaminants is a possibility. The HOA1879-011 and -012 have a 0.060 in.(1.52 mm) dia. detector aperture, while the HOA1879-015 has a 0.010 in.(.25 mm) x 0.040 in. (1.02 mm) vertical aperture in front of the detector. This feature is ideal for use in applications where maximum position resolution is desired. The HOA1879 series employs plastic molded components. For additional component information see SEP8506 and SDP8406.

Housing material is IR transmissive polysulfone. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

OUTLINE DIMENSIONS in inches (mm)

Tolerance	3 plc decimals	$\pm 0.010(0.25)$
	2 plc decimals	$\pm 0.020(0.51)$



DIM_051.cdr

HOA1879

Transmissive Sensor

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)						
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	V_F			1.6	V	$I_F=20\text{ mA}$
Reverse Leakage Current	I_R			10	μA	$V_R=3\text{ V}$
DETECTOR						
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	30			V	$I_C=100\text{ }\mu\text{A}$
Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	5.0			V	$I_E=100\text{ }\mu\text{A}$
Collector Dark Current	I_{CE0}			100	nA	$V_{CE}=10\text{ V}, I_F=0$
COUPLED CHARACTERISTICS						
On-State Collector Current	$I_{C(ON)}$				mA	$V_{CE}=5\text{ V}$ $I_F=20\text{ mA}$
HOA1879-011		0.4				
HOA1879-012		1.8				
HOA1879-015		0.5				
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$				V	$I_F=20\text{ mA}$ $I_C=50\text{ }\mu\text{A}$ $I_C=220\text{ }\mu\text{A}$ $I_C=60\text{ }\mu\text{A}$
HOA1879-011				0.4		
HOA1879-012				0.4		
HOA1879-015				0.4		
Rise And Fall Time	t_r, t_f				μs	$V_{CC}=5\text{ V}, I_C=1\text{ mA}$ $R_L=1000\text{ }\Omega$
HOA1879-011, -012, -015			15			

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

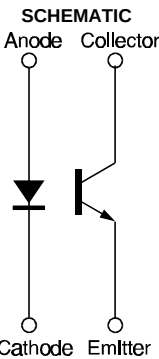
Operating Temperature Range	-40°C to 85°C
Storage Temperature Range	-40°C to 85°C
Soldering Temperature (5 sec)	240°C

IR EMITTER

Power Dissipation	100 mW ⁽¹⁾
Reverse Voltage	3 V
Continuous Forward Current	50 mA

DETECTOR

Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Power Dissipation	100 mW ⁽¹⁾
Collector DC Current	30 mA



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

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HOA1879

Transmissive Sensor

Fig. 1 IRED Forward Bias Characteristics

gra_092.ds4

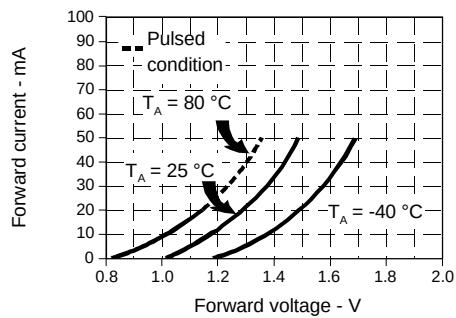


Fig. 2 Non-Saturated Switching Time vs Load Resistance

gra_096.ds4

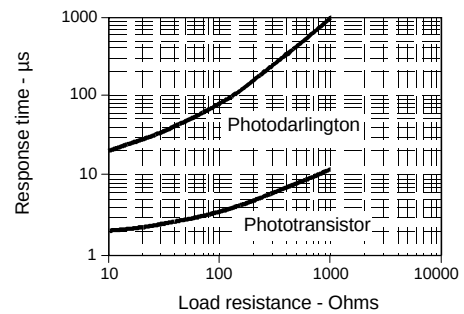


Fig. 3 Dark Current vs Temperature

gra_301.cdr

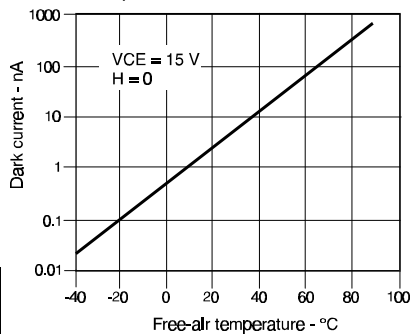
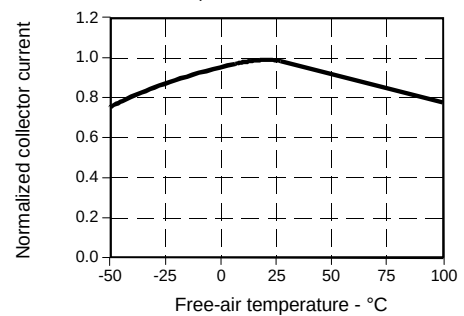


Fig. 4 Collector Current vs Ambient Temperature

gra_095.ds4



All Performance Curves Show Typical Values

HOA1879

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